



JIEJIE MICROELECTRONICS CO. , Ltd

: ì ñ h ^ y brĀ ML P HZ G ML P] Z O0 0 / 2 1 ML P] MH • t bØ \$ 00 x 6-Œ \$ •5



> dZ/ > , Z d Zt^d/ ^

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
5HYHUVH ZRUNLQJ Y5ROWDJH		9				9
5HYHUVH EUHDNGRZQ5YROWDJH		9				9
5HYHUVH OHDNDJH FXUJHQW99		,				\$
3HDN SXOVH FXUJHQW		3 W ,				\$
&ODPSLQJ YROWDJH &		,33 \$ 3W V				9
		,33 \$ 3W V				9
-XQFWLRQ FDSDFLWDQFH5:0 99 80+]						S)

Z d/E'^ E sr/ , Z d Z/^d/7^ ž&xZsH^V RWKHUZLVH QRWHG

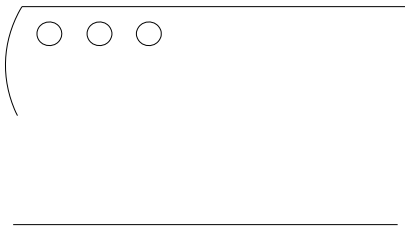
FIG.1:V- I curve character^a :s o/ Vr vt tr

: ì ñ h ^fbr ESD Protection

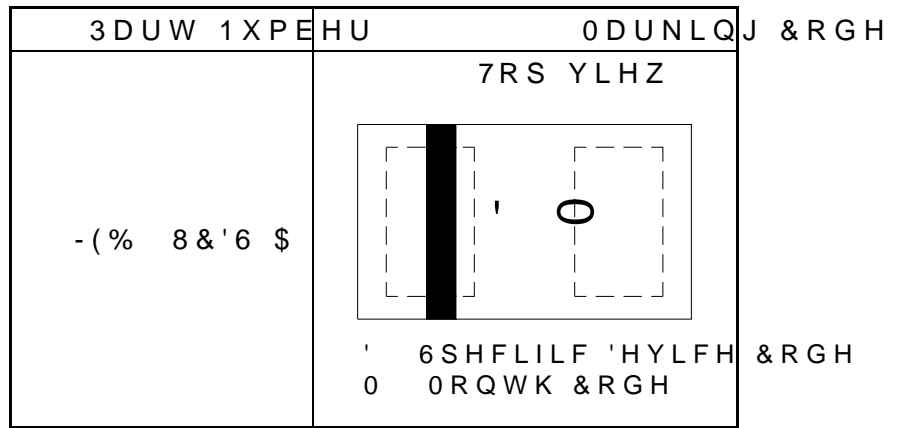
 JieJie Microelectronics CO. , Ltd



d W E Z > /E&KZD d/KEr &Eiòìrî>



D Z</E' K



-LH-LH SURGXFWV DUH QRW GHVLJQHGDQUSXUSGRWIKDDQFQR
 OLPLWDWLRQDIXOLRPRWLDHURVSDQHDEHGLFXOWOLQLQDYL
 DSSOLFDFWLRQVGHYLFHV LQWHQGHAIRU DQJRWODULDSOD
 WKH IDLOXUH RU ODFN RI GHVLUHGRSHWDLQLSKURRQVKHLSQ
 SURSHUW\ GDPDJH RWKHSUHWKDDQVHWVHDEVDKI LQH-D SIS S
 GRFXPHQWDWLRQ :HGDLEDQVHLVHJUKDDQOGEHRGSHWRIGXFWRV XV
 SXUSR VH QRW H[SULQVDSOLHVD EBUWKLRQHGRFXPHQWDWLRQQR
 DQ\FODLPV RU GDPDJHVSURGXEWJRXWVHGVLQRDVSISQSEFWLO\
 -LH-LH DV VHW IRUWK LQ DSSOLFDEOH -LH-LH GRFXPHQWD